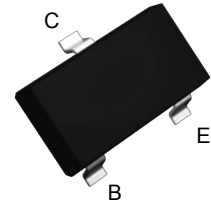


Features

- Low $V_{CE(sat)}$
- h_{FE} characterized up to 1A for high current gain hold up
- For general amplification



SOT-23

Absolute Maximum Ratings ($T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CBO}	170	V
Collector - Emitter Voltage	V_{CEO}	150	V
Emitter - Base Voltage	V_{EBO}	5	V
Collector Current - Continuous	I_C	1	A
Collector Power Dissipation	P_C	250	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	500	$^{\circ}C/W$
Junction Temperature	T_J	-55 to +150	$^{\circ}C$
Storage Temperature	T_{STG}	-55 to +150	$^{\circ}C$

Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=100\mu A, I_E=0$	170	-	V
Collector-Emitter Breakdown Voltage ¹	$V_{(BR)CEO}$	$I_C=10mA, I_B=0$	150	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=100\mu A, I_C=0$	5	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB}=150V, I_E=0$	-	0.1	μA
Collector Cut-off Current	I_{CES}	$V_{CB}=150V, V_{BE}=0$	-	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=4V, I_C=0$	-	0.1	μA
DC Current Gain ¹	h_{FE1}	$V_{CE}=10V, I_C=1mA$	100	-	-
	h_{FE2}	$V_{CE}=10V, I_C=250mA$	100	300	-
	h_{FE3}	$V_{CE}=10V, I_C=500mA$	50	-	-
	h_{FE4}	$V_{CE}=10V, I_C=1A$	10	-	-
Collector-Emitter Saturation Voltage ¹	$V_{CE(sat)1}$	$I_C=250mA, I_B=25mA$	-	0.2	V
	$V_{CE(sat)2}$	$I_C=500mA, I_B=50mA$	-	0.3	
Base-Emitter Turn-On Voltage ¹	$V_{BE(on)}$	$V_{CE}=10V, I_C=500mA$	-	1	V
Base-Emitter Saturation Voltage ¹	$V_{BE(sat)}$	$I_C=500mA, I_B=50mA$	-	1	V
Transition Frequency	f_T	$V_{CE}=10V, I_C=50mA, F=100MHz$	100	-	MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, F=1MHz$	-	10	pF

Note:

1. Pulse test: pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

Typical Electrical and Thermal Characteristic Curves

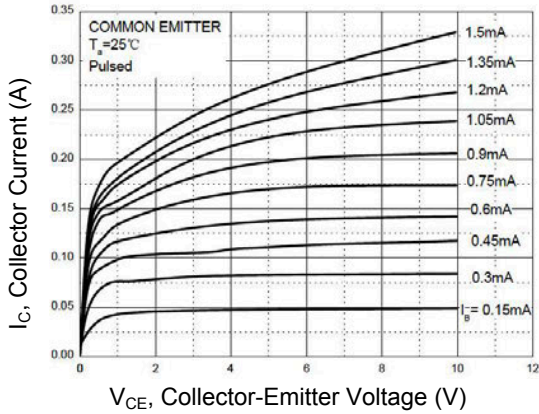


Figure 1. Collector Current vs. Collector - Emmitter Voltage

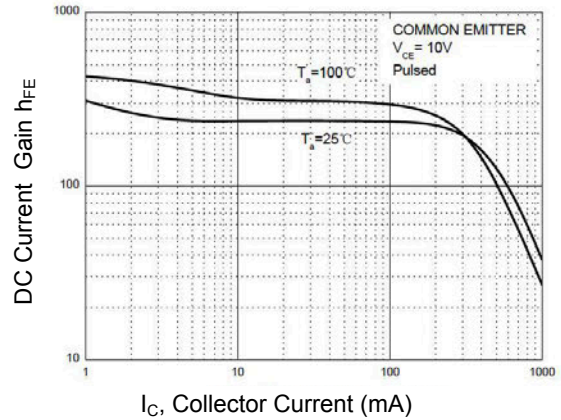


Figure 2. DC Current Gain vs Collector Current

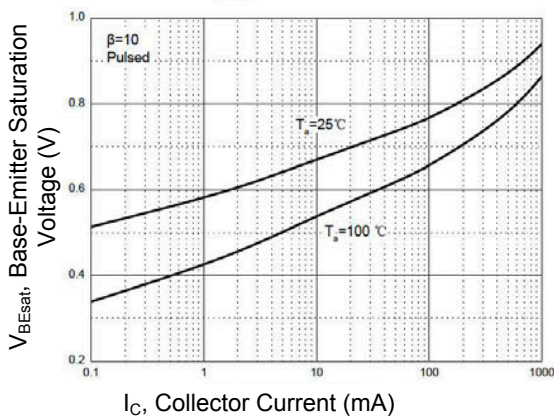


Figure 3. Base-Emmitter Saturation Voltage vs. Collector Current

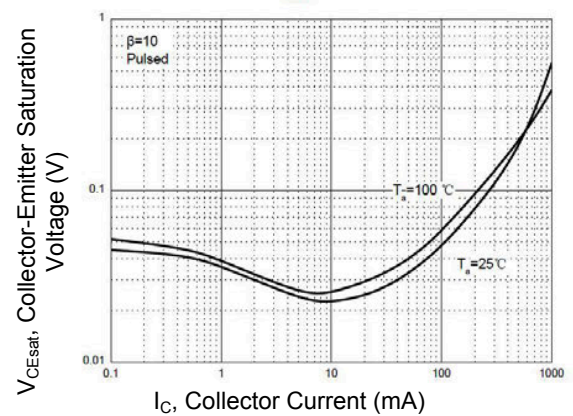


Figure 4. Collector-Emmitter Saturation Voltage vs. Collector Current

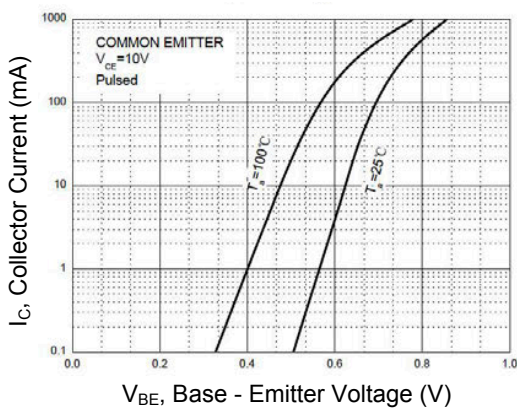


Figure 5. Collector Current vs. Base - Emmitter Voltage

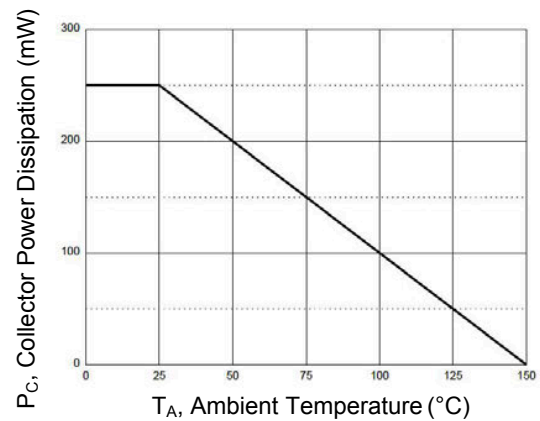


Figure 6. Power Dissipation vs Ambient Temperature

Typical Electrical and Thermal Characteristic Curves

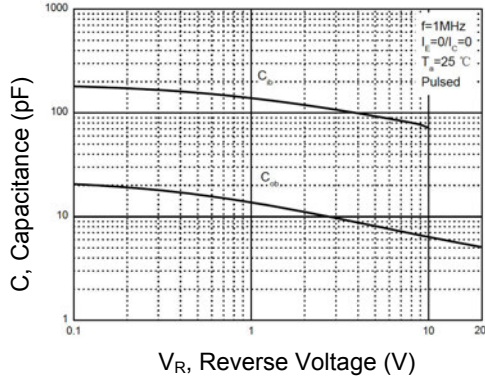
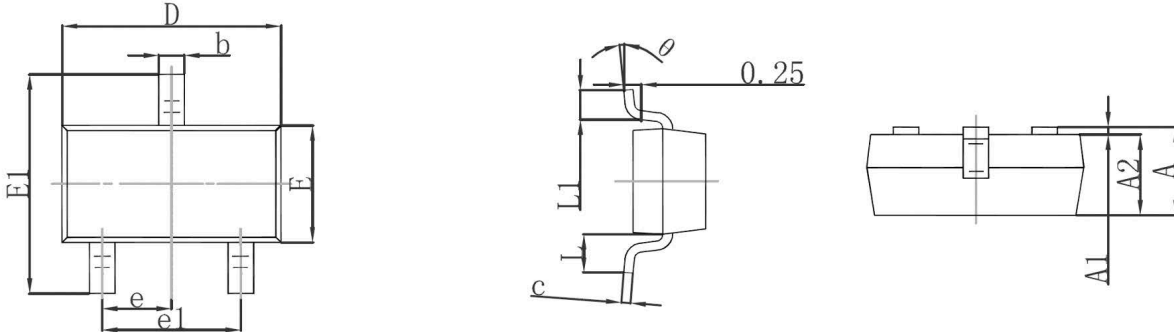


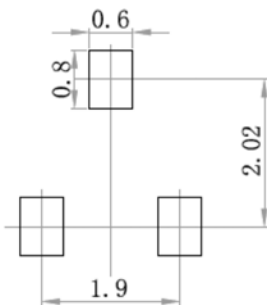
Figure 7. Capacitance Characteristics

Package Outline Dimensions (SOT-23)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Recommended Pad Layout



Note:

1. Controlling dimensions: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

Order Information

Device	Package	Marking	Quantity	HSF Status
MMBT495	SOT-23	495	3,000pcs / Reel	RoHS Compliant